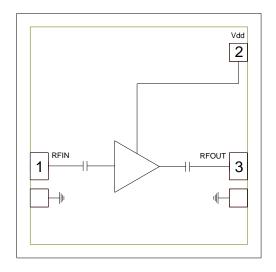


6-18 GHz Low Noise Amplifier

Product Overview

The CMD264 is a broadband MMIC low noise amplifier ideally suited for EW and communications systems where small size and low power consumption are needed. The broadband device delivers greater than 25 dB of gain with a corresponding output 1 dB compression point of +10 dBm and a noise figure of 1.6 dB. The CMD264 is a 50 ohm matched design eliminating the need for external DC blocks and RF port matching. The CMD264 amplifier is the perfect alternative to costly hybrid amplifiers.

Functional Block Diagram



Key Features

- Ultra Low Noise Figure
- High Gain Broadband Performance
- Single Supply Voltage: +3.0 V @ 63 mA
- Small Die Size: 1350 um x 1350 um

Ordering Information

| Part No. | Description |
|----------|--|
| CMD264 | 6-18 GHz Low Noise Amplifier, 100 Piece WP Sample |

Electrical Performance (V_{dd} = 3.0 V, T_A = 25 °C)

| Parameter | Min | Тур | Max | Units |
|--------------------|-----|--------|-----|-------|
| Frequency Range | | 6 - 18 | | GHz |
| Gain | | 26 | | dB |
| Noise Figure | | 1.6 | | dB |
| Input Return Loss | | 10 | | dB |
| Output Return Loss | | 14 | | dB |
| Output P1dB | | 11 | | dBm |
| Supply Current | | 63 | | mA |



Absolute Maximum Ratings

| Parameter | Rating |
|-------------------------------------|---------------|
| Drain Voltage, V _{dd} | 5.0 V |
| RF Input Power | +20 dBm |
| Channel Temperature, Tch | 150 °C |
| Power Dissipation, Pdiss | 540 mW |
| Thermal Resistance, θ _{JC} | 120 °C/W |
| Operating Temperature | -55 to 85 °C |
| Storage Temperature | -55 to 150 °C |
| ESD Sensitivity (HBM) | Class 1A |

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

| Parameter | Min | Тур | Max | Units |
|-----------------|-----|-----|-----|-------|
| V_{dd} | 2.0 | 3.0 | 4.5 | V |
| l _{dd} | | 63 | | mA |

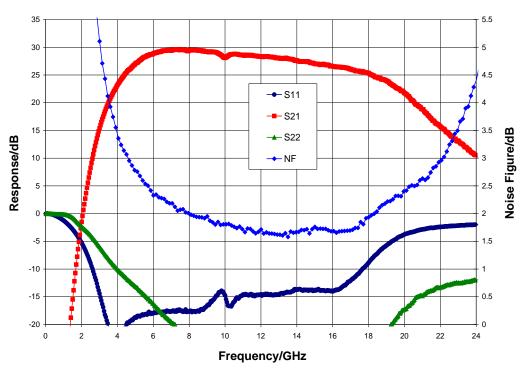
Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications (V_{dd} = 3.0 V, T_A = 25 °C)

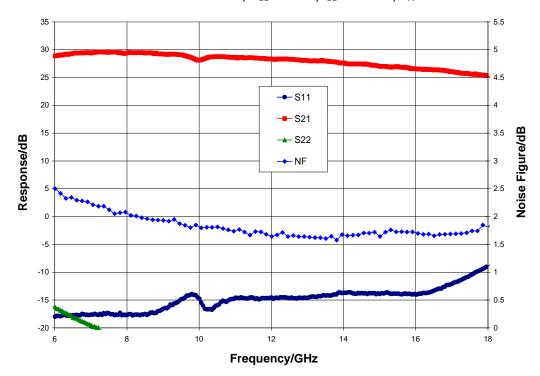
| Parameter | Min | Тур | Max | Min | Тур | Max | Units |
|--------------------------------------|-----|--------|-----|-----|---------|-----|-------|
| Frequency Range | | 6 - 12 | | | 12 - 18 | | GHz |
| Gain | 25 | 29 | 33 | 22 | 27 | 31 | dB |
| Noise Figure | | 2.0 | 2.9 | | 1.6 | 2.3 | dB |
| Input Return Loss | | 15 | | | 10 | | dB |
| Output Return Loss | | 18 | | | 20 | | dB |
| Output P1dB | | 13 | | | 13 | | dBm |
| Output IP3 | | 27 | | | 25 | | dBm |
| Supply Current | 44 | 63 | 82 | 44 | 63 | 82 | mA |
| Gain Temperature Coefficient | | 0.015 | | | 0.015 | | dB/°C |
| Noise Figure Temperature Coefficient | | 0.008 | | | 0.008 | | dB/°C |



Broadband Performance, V_{dd} = 3.0 V, I_{dd} = 63 mA, T_A = 25 °C

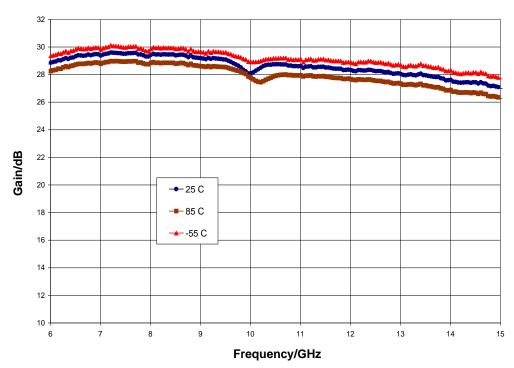


Narrow-band Performance, V_{dd} = 3.0 V, I_{dd} = 63 mA, T_A = 25 °C

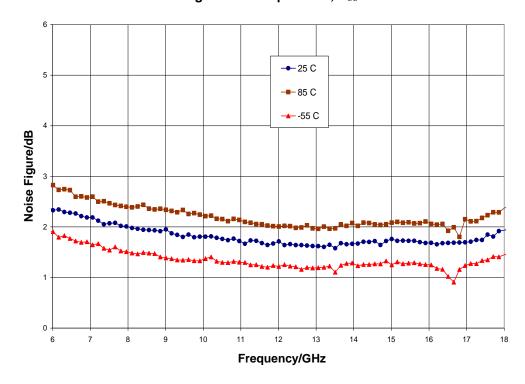




Gain vs. Temperature, V_{dd} = 3.0 V

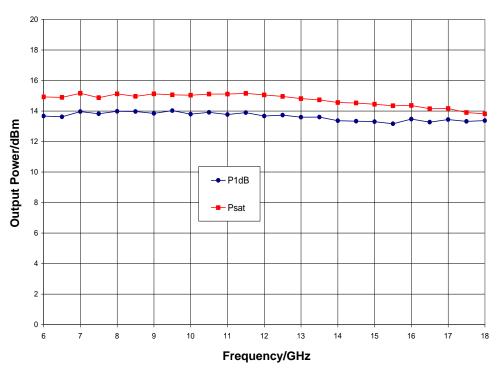


Noise Figure vs. Temperature, $V_{dd} = 3.0 \text{ V}$

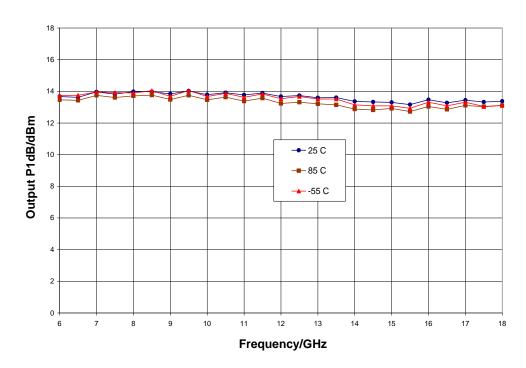




Output Power, V_{dd} = 3.0 V, I_{dd} = 63 mA, T_A = 25 °C

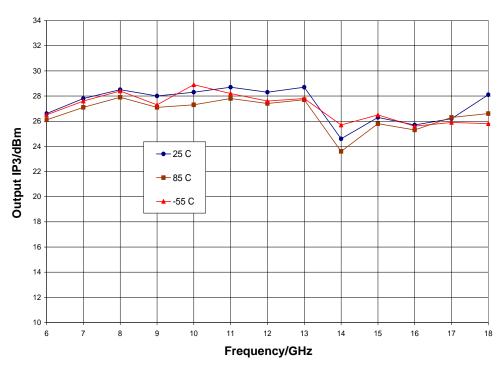


Output P1dB vs. Temperature, V_{dd} = 3.0 V, I_{dd} = 63 mA





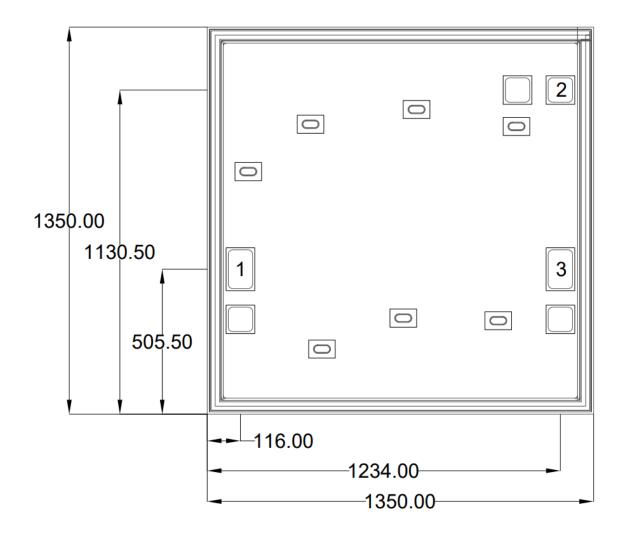
Output IP3 vs. Temperature, $V_{dd} = 3.0 \text{ V}$, $I_{dd} = 63 \text{ mA}$





Mechanical Information

Die Outline (all dimensions in microns)



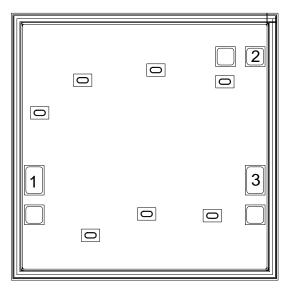
Notes:

- 1. No connection required for unlabeled pads
- 2. Backside is RF and DC ground
- 3. Backside and bond pad metal: Gold
- 4. Die is 100 microns thick
- 5. DC bond pad (2) is 100 microns square
- 6. RF bond pads (1, 3) are 100 x 150 microns



Pad Description

Pad Diagram



Functional Description

| Pad | Function | Description | Schematic |
|----------|-----------------|---|---|
| 1 | RF in | DC blocked and 50 ohm matched | RF in O |
| 2 | V _{dd} | Power supply voltage Decoupling and bypass caps required | Vdd ——————————————————————————————————— |
| 3 | RF out | DC blocked and 50 ohm matched | |
| Backside | Ground | Connect to RF / DC ground | GND = |



Applications Information

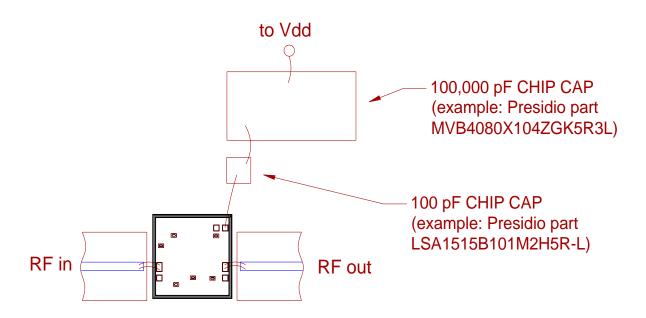
Assembly Guidelines

The backside of the CMD264 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require double bond wires as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Applications Information

Biasing and Operation

The CMD264 is biased with a positive drain supply. Performance is optimized when the drain voltage is set to +3.0 V, though it may be set to a minimum of +2.0 V and a maximum of +4.5 V.

Turn ON procedure:

1. Apply drain voltage V_{dd} and set to +3 V

Turn OFF procedure:

1. Turn off drain voltage V_{dd}

RF power can be applied at any time.



Handling Precautions

| Parameter | Rating | Standard | On God | |
|------------------------------|----------|--------------------------|----------------------------------|--|
| ESD – Human Body Model (HBM) | Class 1A | ESDA / JEDEC JS-001-2012 | Caution! ESD-Sensitive Device | |

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- SVHC Free
- Halogen Free
- PFOS Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u> Tel: 1-844-890-8163

Email: customer.support@gorvo.com

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